Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

0.450 inches

Mounting Facility Quantity:

1

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Do-5

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

Between 0.667 inches and 0.687 inches

Thready Qty Per Inch (tpi):

28

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 working peak reverse voltage, peak total value

Current Rating Per Characteristic:

35.00 amperes forward current, average absolute

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 threaded stud and 1 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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